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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	10MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	12
Program Memory Size	768B (512 x 12)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	25 x 8
Voltage - Supply (Vcc/Vdd)	4.5V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	18-SOIC (0.295", 7.50mm Width)
Supplier Device Package	18-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c54a-10-so



PIC16C5X

8-Bit EPROM/ROM-Based CMOS Microcontrollers

1.0 GENERAL DESCRIPTION

The PIC16C5X from Microchip Technology is a family of low cost, high performance, 8-bit fully static, EPROM/ROM-based CMOS microcontrollers. It employs a RISC architecture with only 33 single word/single cycle instructions. All instructions are single cycle except for program branches which take two cycles. The PIC16C5X delivers performance in an order of magnitude higher than its competitors in the same price category. The 12-bit wide instructions are highly symmetrical resulting in 2:1 code compression over other 8-bit microcontrollers in its class. The easy to use and easy to remember instruction set reduces development time significantly.

The PIC16C5X products are equipped with special features that reduce system cost and power requirements. The Power-on Reset (POR) and Device Reset Timer (DRT) eliminate the need for external RESET circuitry. There are four oscillator configurations to choose from, including the power saving LP (Low Power) oscillator and cost saving RC oscillator. Power saving SLEEP mode, Watchdog Timer and Code Protection features improve system cost, power and reliability.

The UV erasable Cerdip packaged versions are ideal for code development, while the cost effective One Time Programmable (OTP) versions are suitable for production in any volume. The customer can take full advantage of Microchip's price leadership in OTP microcontrollers, while benefiting from the OTP's flexibility.

The PIC16C5X products are supported by a full featured macro assembler, a software simulator, an in-circuit emulator, a low cost development programmer and a full featured programmer. All the tools are supported on IBM® PC and compatible machines.

1.1 Applications

The PIC16C5X series fits perfectly in applications ranging from high speed automotive and appliance motor control to low power remote transmitters/receivers, pointing devices and telecom processors. The EPROM technology makes customizing application programs (transmitter codes, motor speeds, receiver frequencies, etc.) extremely fast and convenient. The small footprint packages, for through hole or surface mounting, make this microcontroller series perfect for applications with space limitations. Low cost, low power, high performance ease of use and I/O flexibility make the PIC16C5X series very versatile even in areas where no microcontroller use has been considered before (e.g., timer functions, replacement of "glue" logic in larger systems, co-processor applications).

4.4 RC Oscillator

For timing insensitive applications, the RC device option offers additional cost savings. The RC oscillator frequency is a function of the supply voltage, the resistor (R_{EXT}) and capacitor (C_{EXT}) values, and the operating temperature. In addition to this, the oscillator frequency will vary from unit to unit due to normal process parameter variation. Furthermore, the difference in lead frame capacitance between package types will also affect the oscillation frequency, especially for low C_{EXT} values. The user also needs to take into account variation due to tolerance of external R and C components used.

Figure 4-5 shows how the R/C combination is connected to the PIC16C5X. For R_{EXT} values below 2.2 k Ω , the oscillator operation may become unstable, or stop completely. For very high R_{EXT} values (e.g., 1 M Ω) the oscillator becomes sensitive to noise, humidity and leakage. Thus, we recommend keeping R_{EXT} between 3 k Ω and 100 k Ω .

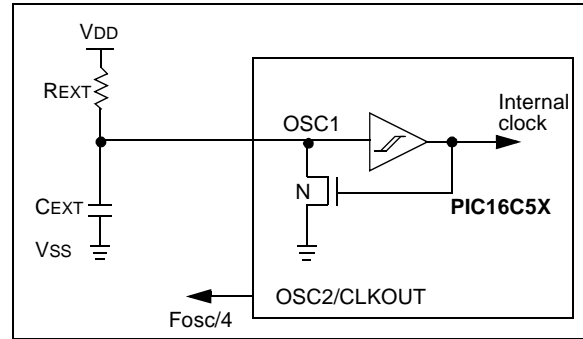
Although the oscillator will operate with no external capacitor ($C_{EXT} = 0$ pF), we recommend using values above 20 pF for noise and stability reasons. With no or small external capacitance, the oscillation frequency can vary dramatically due to changes in external capacitances, such as PCB trace capacitance or package lead frame capacitance.

The Electrical Specifications sections show RC frequency variation from part to part due to normal process variation. The variation is larger for larger R (since leakage current variation will affect RC frequency more for large R) and for smaller C (since variation of input capacitance will affect RC frequency more).

Also, see the Electrical Specifications sections for variation of oscillator frequency due to V_{DD} for given R_{EXT}/C_{EXT} values as well as frequency variation due to operating temperature for given R, C, and V_{DD} values.

The oscillator frequency, divided by 4, is available on the OSC2/CLKOUT pin, and can be used for test purposes or to synchronize other logic.

FIGURE 4-5: RC OSCILLATOR MODE



Note: If you change from this device to another device, please verify oscillator characteristics in your application.

PIC16C5X

FIGURE 5-3: TIME-OUT SEQUENCE ON POWER-UP ($\overline{\text{MCLR}}$ NOT TIED TO VDD)

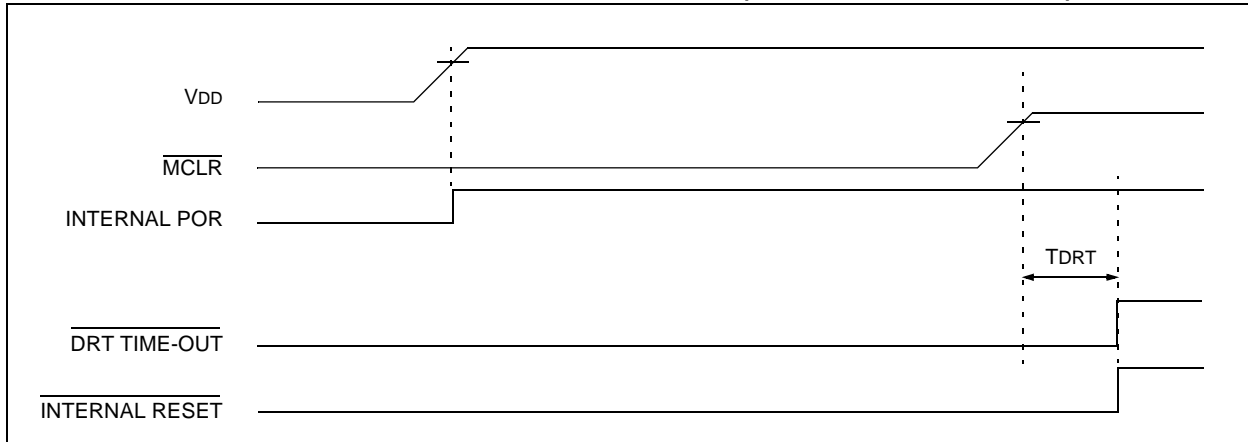


FIGURE 5-4: TIME-OUT SEQUENCE ON POWER-UP ($\overline{\text{MCLR}}$ TIED TO VDD): FAST VDD RISE TIME

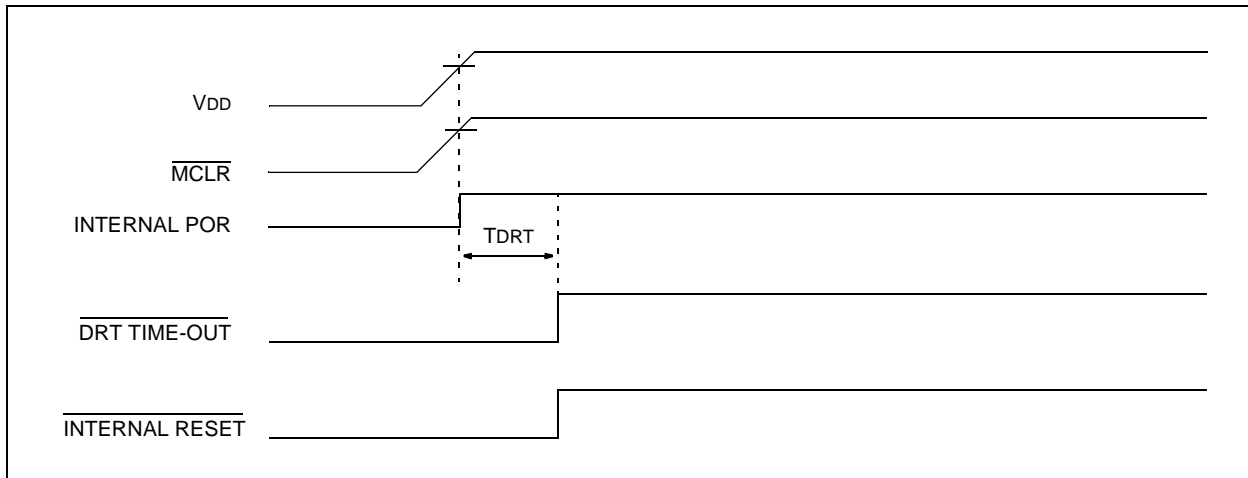
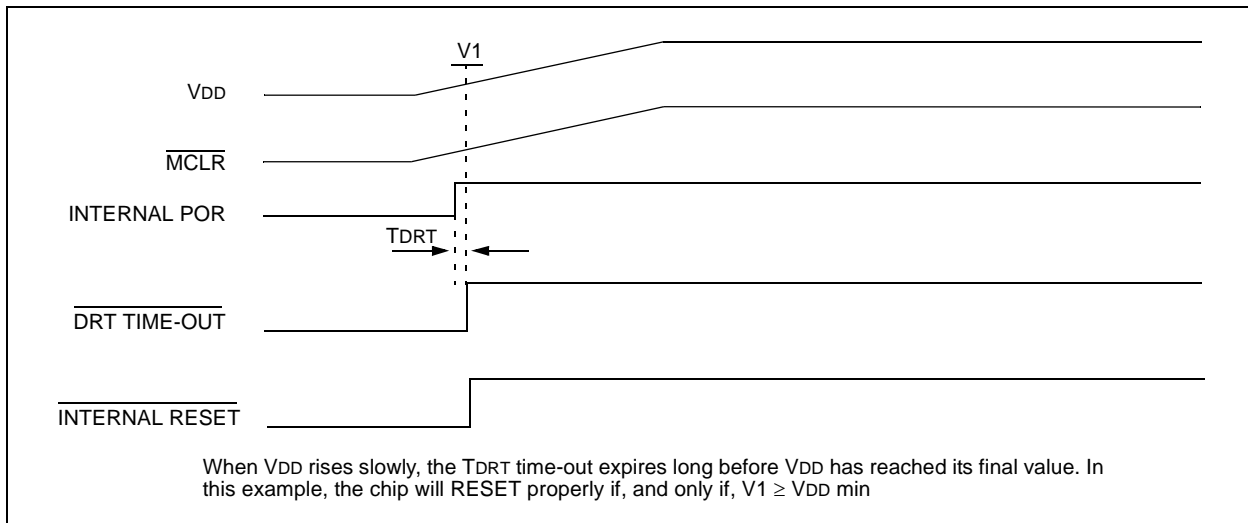


FIGURE 5-5: TIME-OUT SEQUENCE ON POWER-UP ($\overline{\text{MCLR}}$ TIED TO VDD): SLOW VDD RISE TIME



PIC16C5X

6.2 Data Memory Organization

Data memory is composed of registers, or bytes of RAM. Therefore, data memory for a device is specified by its register file. The register file is divided into two functional groups: Special Function Registers and General Purpose Registers.

The Special Function Registers include the TMR0 register, the Program Counter (PC), the Status Register, the I/O registers (ports) and the File Select Register (FSR). In addition, Special Purpose Registers are used to control the I/O port configuration and prescaler options.

The General Purpose Registers are used for data and control information under command of the instructions.

For the PIC16C54, PIC16CR54, PIC16C56 and PIC16CR56, the register file is composed of 7 Special Function Registers and 25 General Purpose Registers (Figure 6-4).

For the PIC16C55, the register file is composed of 8 Special Function Registers and 24 General Purpose Registers.

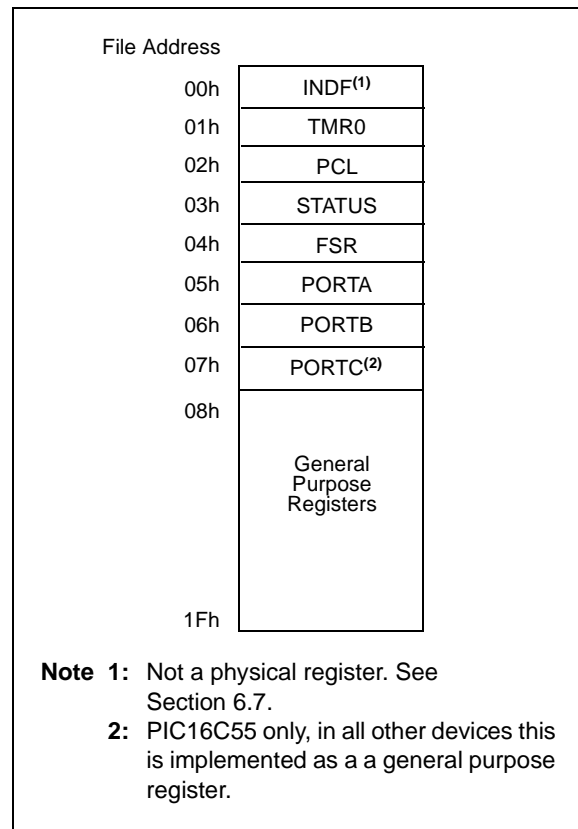
For the PIC16C57 and PIC16CR57, the register file is composed of 8 Special Function Registers, 24 General Purpose Registers and up to 48 additional General Purpose Registers that may be addressed using a banking scheme (Figure 6-5).

For the PIC16C58 and PIC16CR58, the register file is composed of 7 Special Function Registers, 25 General Purpose Registers and up to 48 additional General Purpose Registers that may be addressed using a banking scheme (Figure 6-6).

6.2.1 GENERAL PURPOSE REGISTER FILE

The register file is accessed either directly or indirectly through the File Select Register (FSR). The FSR Register is described in Section 6.7.

FIGURE 6-4: PIC16C54, PIC16CR54, PIC16C55, PIC16C56, PIC16CR56 REGISTER FILE MAP



PIC16C5X

NOTES:

7.6 I/O Programming Considerations

7.6.1 BI-DIRECTIONAL I/O PORTS

Some instructions operate internally as read followed by write operations. The BCF and BSF instructions, for example, read the entire port into the CPU, execute the bit operation and re-write the result. Caution must be used when these instructions are applied to a port where one or more pins are used as input/outputs. For example, a BSF operation on bit5 of PORTB will cause all eight bits of PORTB to be read into the CPU, bit5 to be set and the PORTB value to be written to the output latches. If another bit of PORTB is used as a bi-directional I/O pin (say bit0) and it is defined as an input at this time, the input signal present on the pin itself would be read into the CPU and rewritten to the data latch of this particular pin, overwriting the previous content. As long as the pin stays in the Input mode, no problem occurs. However, if bit0 is switched into Output mode later on, the content of the data latch may now be unknown.

Example 7-1 shows the effect of two sequential read-modify-write instructions (e.g., BCF, BSF, etc.) on an I/O port.

A pin actively outputting a high or a low should not be driven from external devices at the same time in order to change the level on this pin ("wired-or", "wired-and"). The resulting high output currents may damage the chip.

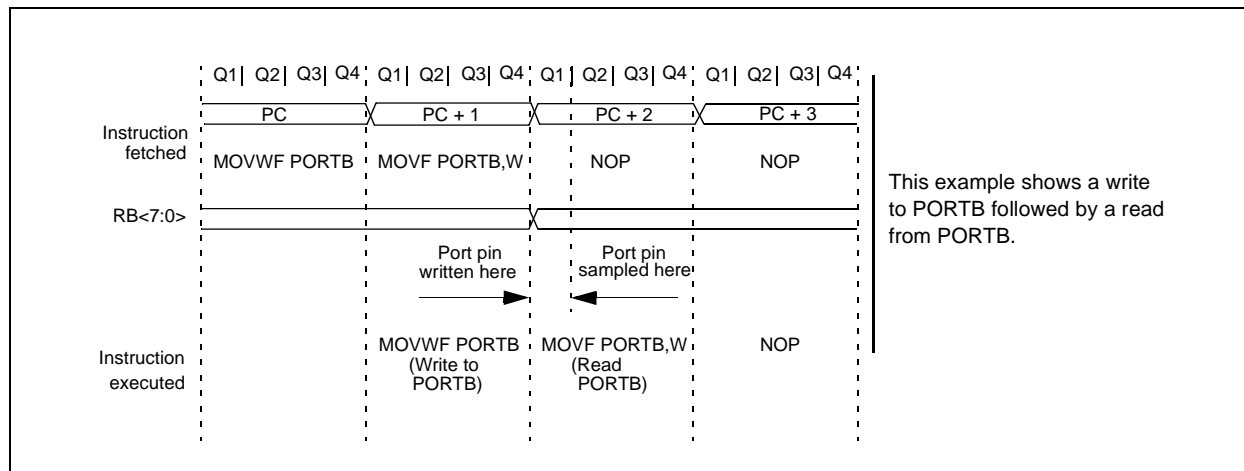
EXAMPLE 7-1: READ-MODIFY-WRITE INSTRUCTIONS ON AN I/O PORT

```
;Initial PORT Settings
; PORTB<7:4> Inputs
; PORTB<3:0> Outputs
;PORTB<7:6> have external pull-ups and are
;not connected to other circuitry
;
;
;          PORT latch  PORT pins
;          -----
BCF  PORTB, 7  ;01pp pppp  11pp pppp
BCF  PORTB, 6  ;10pp pppp  11pp pppp
MOVLW H'3F'    ;
TRIS  PORTB    ;10pp pppp  10pp pppp
;
;Note that the user may have expected the pin
;values to be 00pp pppp. The 2nd BCF caused
;RB7 to be latched as the pin value (High).
```

7.6.2 SUCCESSIVE OPERATIONS ON I/O PORTS

The actual write to an I/O port happens at the end of an instruction cycle, whereas for reading, the data must be valid at the beginning of the instruction cycle (Figure 7-2). Therefore, care must be exercised if a write followed by a read operation is carried out on the same I/O port. The sequence of instructions should allow the pin voltage to stabilize (load dependent) before the next instruction, which causes that file to be read into the CPU, is executed. Otherwise, the previous state of that pin may be read into the CPU rather than the new state. When in doubt, it is better to separate these instructions with a NOP or another instruction not accessing this I/O port.

FIGURE 7-2: SUCCESSIVE I/O OPERATION



REGISTER 9-2: CONFIGURATION WORD FOR PIC16C54/C55/C56/C57

—	—	—	—	—	—	—	—	CP	WDTE	FOSC1	FOSC0
bit 11											bit 0

bit 11-4: **Unimplemented:** Read as '0'

bit 3: **CP:** Code protection bit.
 1 = Code protection off
 0 = Code protection on

bit 2: **WDTE:** Watchdog timer enable bit
 1 = WDT enabled
 0 = WDT disabled

bit 1-0: **FOSC1:FOSC0:** Oscillator selection bits⁽²⁾
 00 = LP oscillator
 01 = XT oscillator
 10 = HS oscillator
 11 = RC oscillator

- Note 1:** Refer to the PIC16C5X Programming Specifications (Literature Number DS30190) to determine how to access the configuration word.
2: PIC16LV54A supports XT, RC and LP oscillator only.

Legend:

R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
-n = Value at POR	1 = bit is set	0 = bit is cleared x = bit is unknown

FIGURE 12-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C54/55/56/57

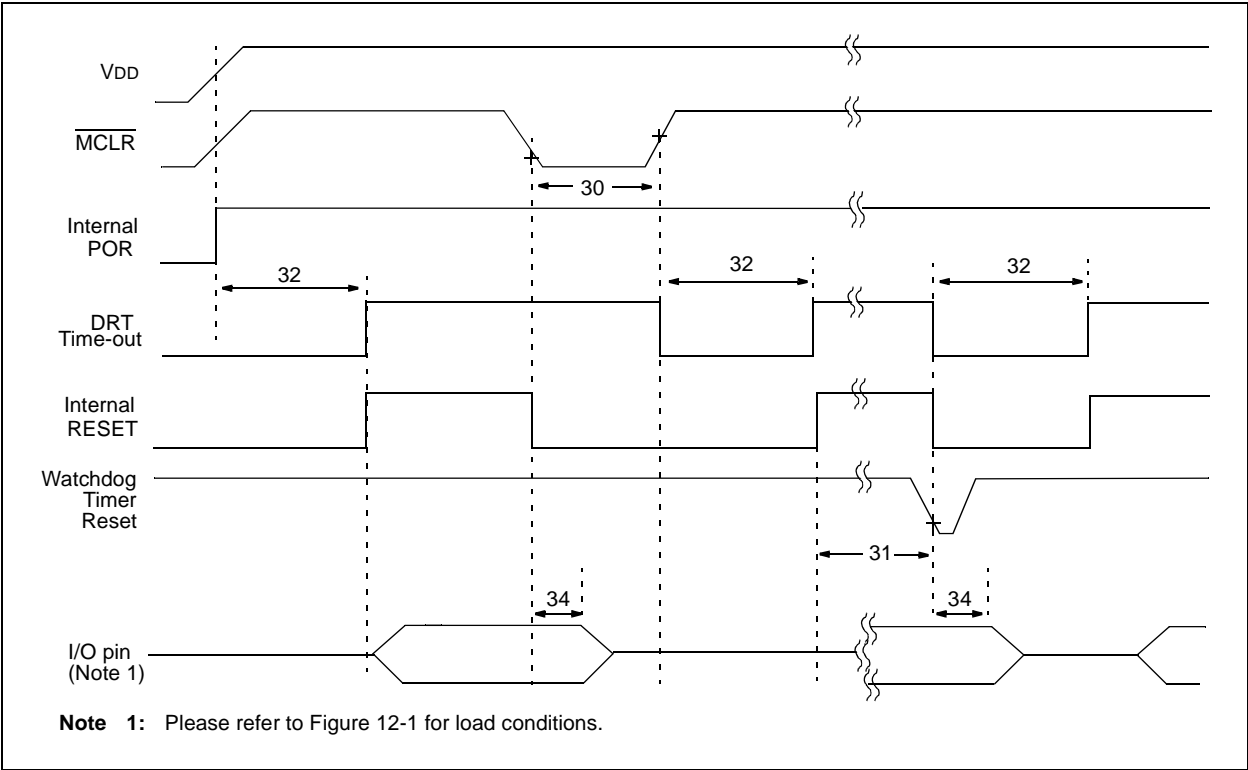


TABLE 12-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C54/55/56/57

Standard Operating Conditions (unless otherwise specified)							
AC Characteristics							
Operating Temperature							
0°C ≤ TA ≤ +70°C for commercial							
-40°C ≤ TA ≤ +85°C for industrial							
-40°C ≤ TA ≤ +125°C for extended							
Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions
30	Tmcl	MCLR Pulse Width (low)	100*	—	—	ns	VDD = 5.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
32	TDRT	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	Tioz	I/O Hi-impedance from MCLR Low	—	—	100*	ns	

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

PIC16C5X

13.2 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

PIC16CR54A-04E, 10E, 20E (Extended)			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ for extended				
Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions
D001	VDD	Supply Voltage RC, XT and LP modes HS mode	3.25 4.5	— —	6.0 5.5	V V	
D002	VDR	RAM Data Retention Voltage ⁽¹⁾	—	1.5*	—	V	Device in SLEEP mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	VSS	—	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	Supply Current ⁽²⁾ RC ⁽³⁾ and XT modes HS mode HS mode	— — —	1.8 4.8 9.0	3.3 10 20	mA mA mA	FOSC = 4.0 MHz, VDD = 5.5V FOSC = 10 MHz, VDD = 5.5V FOSC = 16 MHz, VDD = 5.5V
D020	IPD	Power-down Current ⁽²⁾	— —	5.0 0.8	22 18	μA μA	VDD = 3.25V, WDT enabled VDD = 3.25V, WDT disabled

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.

b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.

3: Does not include current through REXT. The current through the resistor can be estimated by the formula: $I_R = V_{DD}/2R_{EXT}$ (mA) with REXT in kΩ.

13.5 Timing Parameter Symbolology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

- 1. TppS2ppS
- 2. TppS

T	T
F Frequency	T Time

Lowercase letters (pp) and their meanings:

pp	mc MCLR
2 to	osc oscillator
ck CLKOUT	os OSC1
cy cycle time	t0 T0CKI
drt device reset timer	wdt watchdog timer
io I/O port	

Uppercase letters and their meanings:

S	P Period
F Fall	R Rise
H High	V Valid
I Invalid (Hi-impedance)	Z Hi-impedance
L Low	

FIGURE 13-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16CR54A

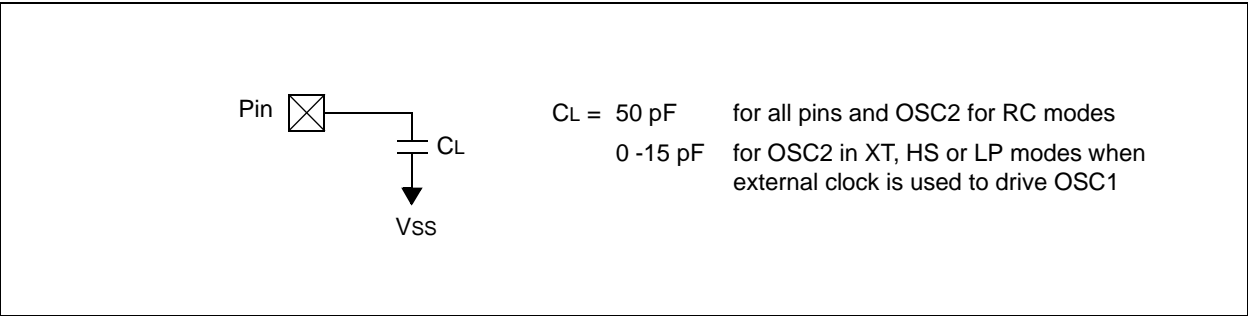


FIGURE 13-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16CR54A

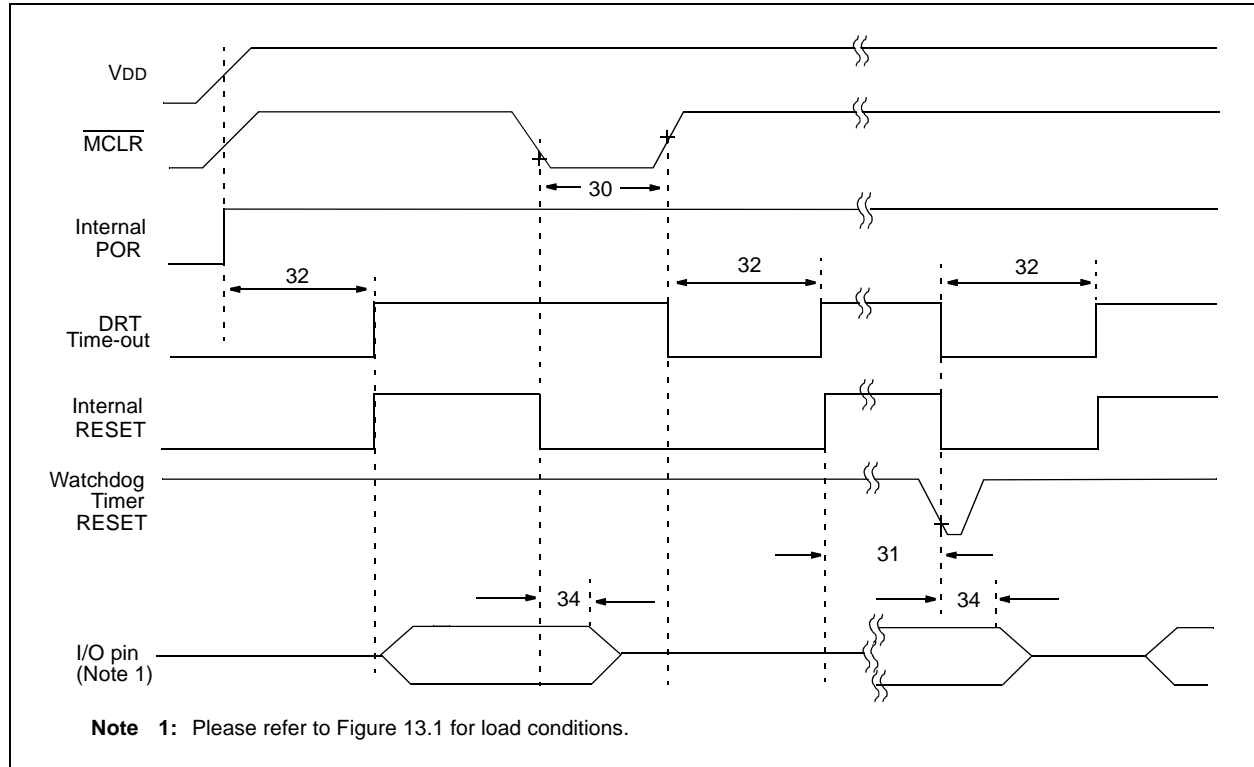


TABLE 13-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16CR54A

Standard Operating Conditions (unless otherwise specified)							
AC Characteristics		Operating Temperature					
		0°C ≤ TA ≤ +70°C for commercial					
		-40°C ≤ TA ≤ +85°C for industrial					
		-40°C ≤ TA ≤ +125°C for extended					
Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions
30	TmCL	MCLR Pulse Width (low)	1.0*	—	—	μs	VDD = 5.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	7.0*	18*	40*	ms	VDD = 5.0V (Comm)
32	TDRT	Device Reset Timer Period	7.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	TioZ	I/O Hi-impedance from MCLR Low	—	—	1.0*	μs	

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 14-2: TYPICAL RC OSC FREQUENCY vs. VDD, CEXT = 20 PF

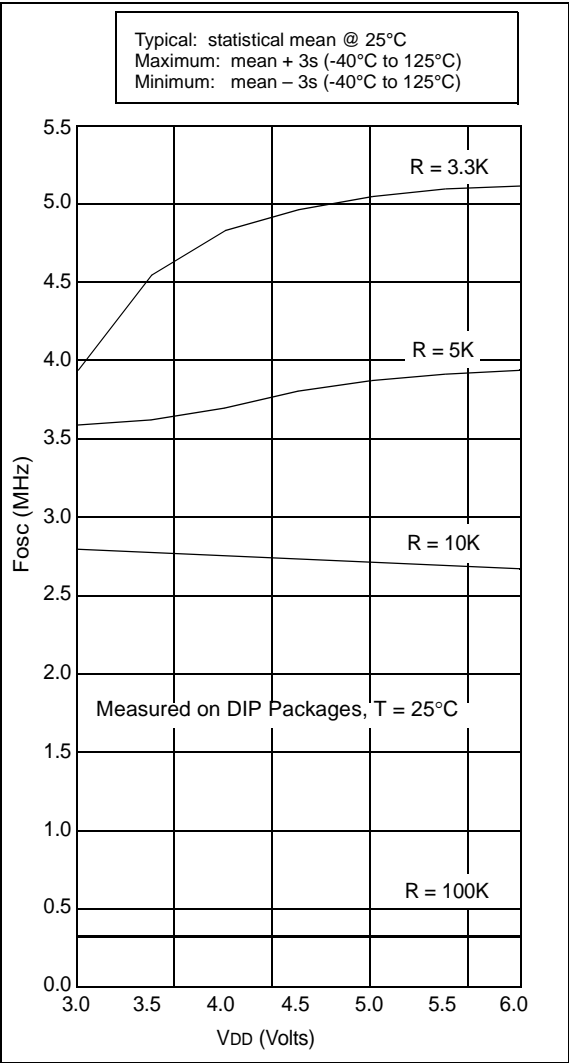
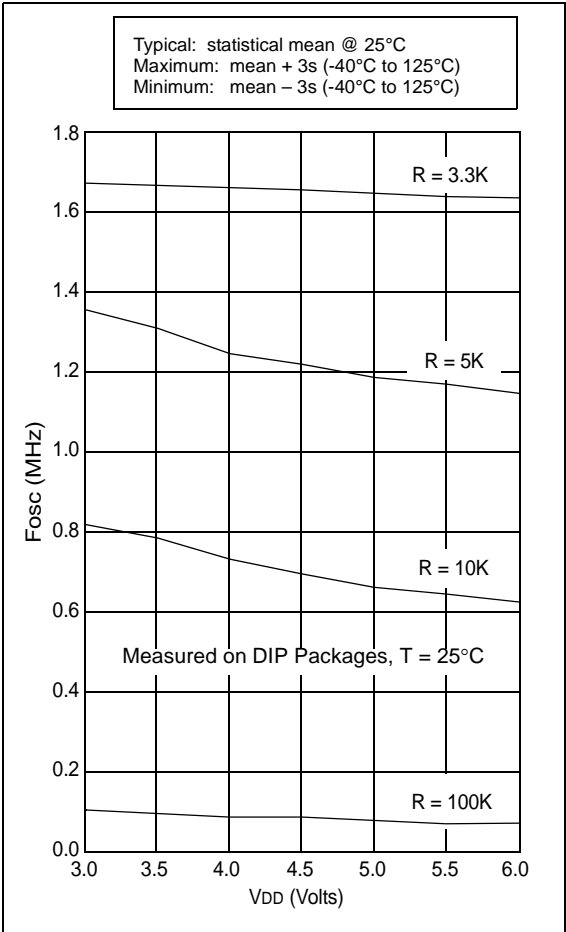


FIGURE 14-3: TYPICAL RC OSC FREQUENCY vs. VDD, CEXT = 100 PF



PIC16C5X

FIGURE 16-12: TYPICAL I_{DD} vs. FREQUENCY (WDT DISABLED, RC MODE @ 100 pF, 25°C)

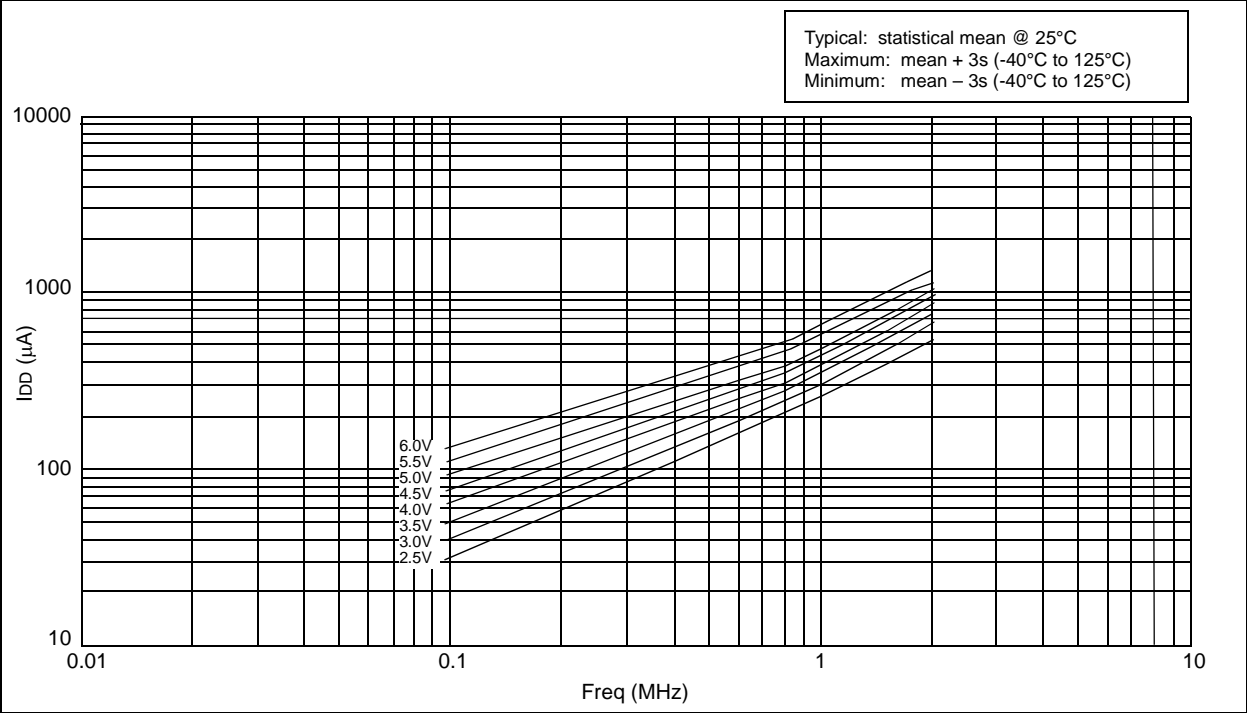


FIGURE 16-13: MAXIMUM I_{DD} vs. FREQUENCY (WDT DISABLED, RC MODE @ 100 pF, -40°C to +85°C)

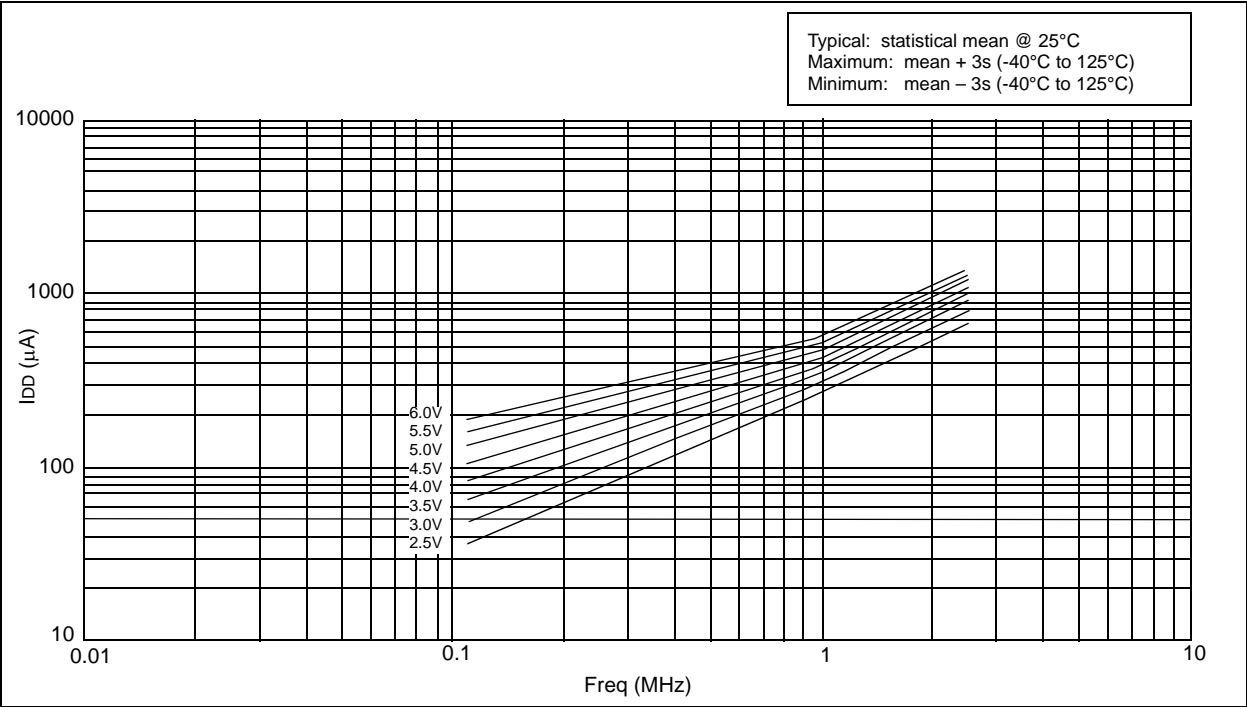


FIGURE 16-14: TYPICAL I_{DD} vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 pF, 25°C)

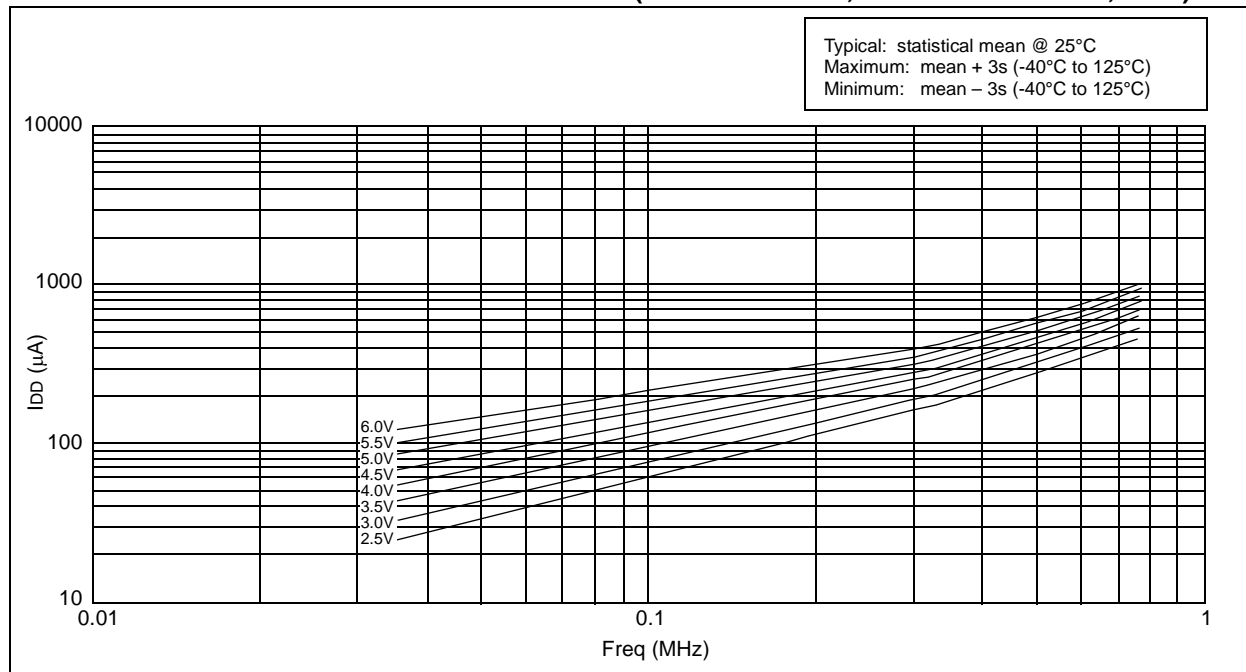
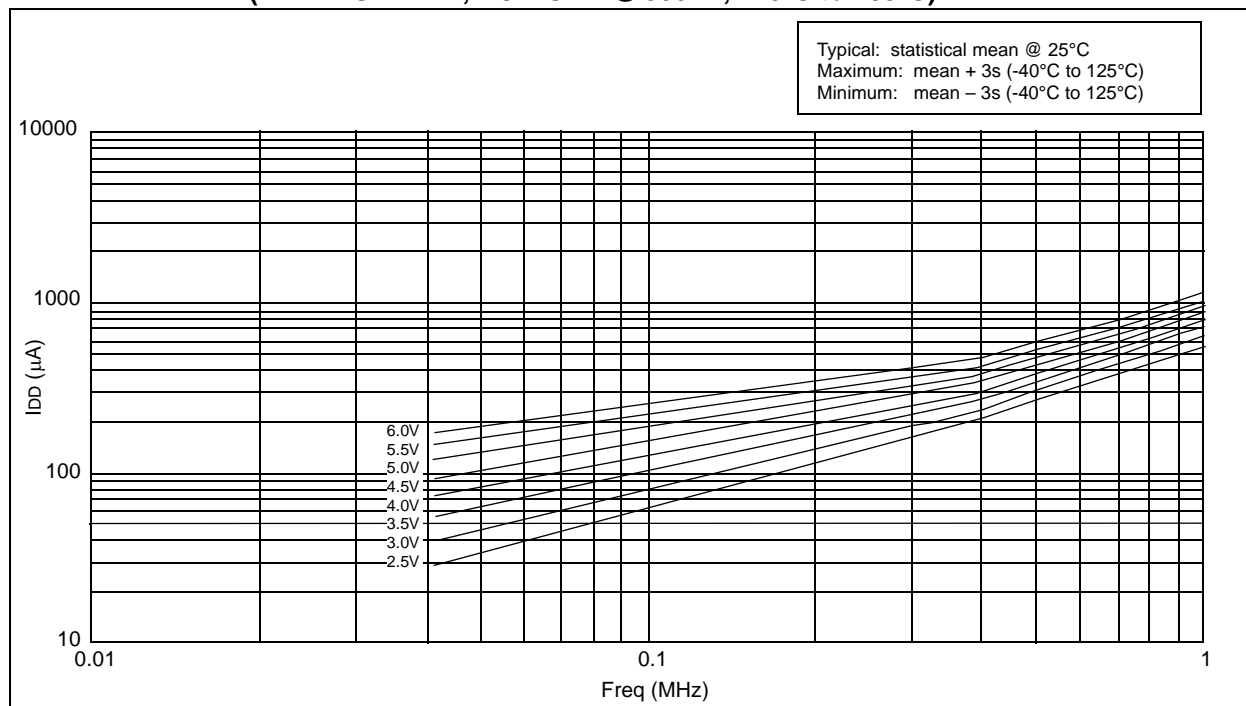


FIGURE 16-15: MAXIMUM I_{DD} vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 pF, -40°C to +85°C)



17.0 ELECTRICAL CHARACTERISTICS - PIC16LC54A

Absolute Maximum Ratings^(†)

Ambient temperature under bias	–55°C to +125°C
Storage temperature	–65°C to +150°C
Voltage on VDD with respect to VSS	0 to +7.5V
Voltage on MCLR with respect to VSS.....	0 to +14V
Voltage on all other pins with respect to VSS	–0.6V to (VDD + 0.6V)
Total power dissipation ⁽¹⁾	800 mW
Max. current out of Vss pin	150 mA
Max. current into VDD pin	100 mA
Max. current into an input pin (T0CKI only)	±500 µA
Input clamp current, I _{IK} (V _I < 0 or V _I > VDD).....	±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O (Port A, B or C)	50 mA
Max. output current sunk by a single I/O (Port A, B or C).....	50 mA

Note 1: Power dissipation is calculated as follows: $P_{dis} = V_{DD} \times \{I_{DD} - \sum I_{OH}\} + \sum \{(V_{DD} - V_{OH}) \times I_{OH}\} + \sum (V_{OL} \times I_{OL})$

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

PIC16C5X

19.2 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-40 (Commercial)⁽¹⁾

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified)				
			Operating Temperature 0°C ≤ TA ≤ +70°C for commercial				
Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions
D030	VIL	Input Low Voltage I/O Ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1	VSS VSS VSS VSS	— — — —	0.8 0.15 VDD 0.15 VDD 0.2 VDD	V V V V	4.5V < VDD ≤ 5.5V HS, 20 MHz ≤ FOSC ≤ 40 MHz
D040	VIH	Input High Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1	2.0 0.85 VDD 0.85 VDD 0.8 VDD	— — — —	VDD VDD VDD VDD	V V V V	4.5V < VDD ≤ 5.5V HS, 20 MHz ≤ FOSC ≤ 40 MHz
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	—	—	V	
D060	IIL	Input Leakage Current^(2,3) I/O ports MCLR MCLR T0CKI OSC1	-1.0 -5.0 — -3.0 -3.0	0.5 — 0.5 0.5 0.5	+1.0 +5.0 +3.0 +3.0 —	μA μA μA μA μA	For VDD ≤ 5.5V: VSS ≤ VPIN ≤ VDD, pin at hi-impedance VPIN = VSS + 0.25V VPIN = VDD VSS ≤ VPIN ≤ VDD VSS ≤ VPIN ≤ VDD, HS
D080	VOL	Output Low Voltage I/O ports	—	—	0.6	V	IOL = 8.7 mA, VDD = 4.5V
D090	VOH	Output High Voltage⁽³⁾ I/O ports	VDD - 0.7	—	—	V	IOH = -5.4 mA, VDD = 4.5V

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

- Note 1:** Device operation between 20 MHz to 40 MHz requires the following: VDD between 4.5V to 5.5V, OSC1 pin externally driven, OSC2 pin not connected and HS oscillator mode and commercial temperatures. For operation between DC and 20 MHz, See Section 17.3.
- 2:** The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.
- 3:** Negative current is defined as coming out of the pin.

PIC16C5X

FIGURE 19-5: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C5X-40

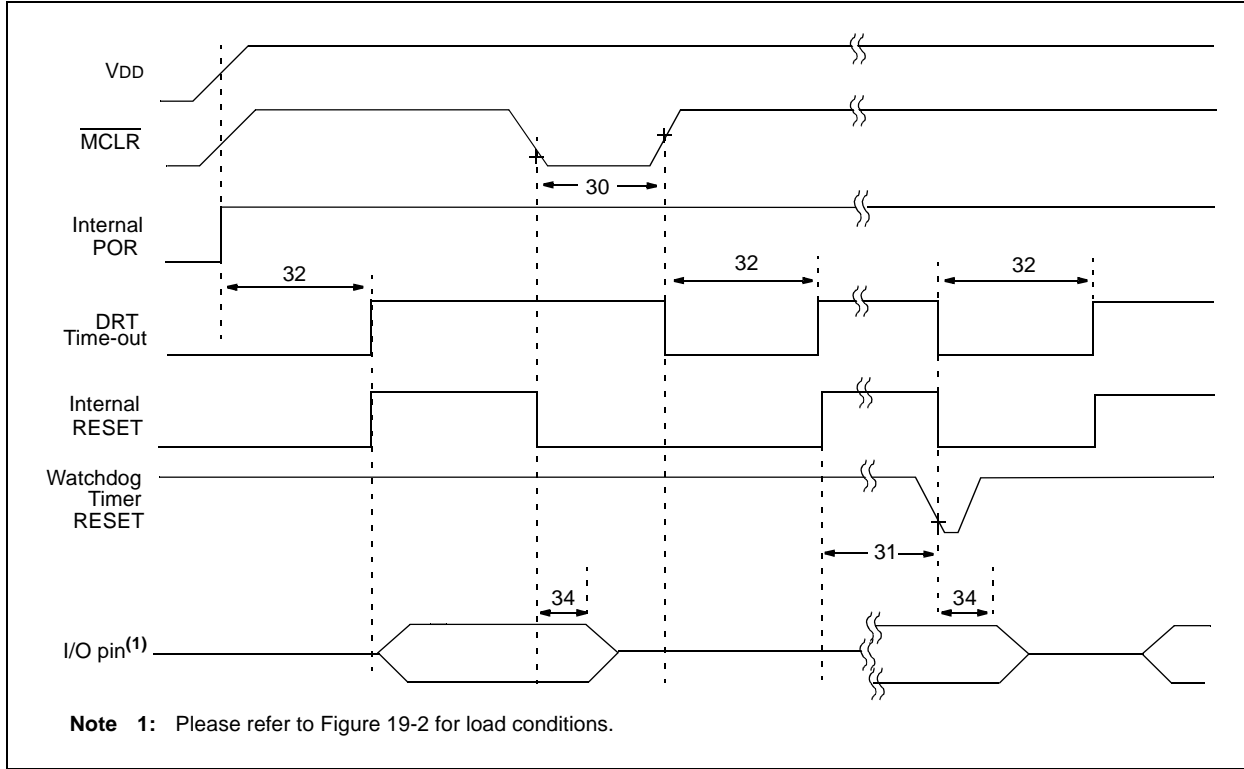


TABLE 19-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C5X-40

Standard Operating Conditions (unless otherwise specified)							
AC Characteristics							
Operating Temperature $0^{\circ}\text{C} \leq T_A \leq +70^{\circ}\text{C}$ (commercial)							
Operating Voltage VDD range is described in Section 19.1.							
Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions
30	Tmcl	MCLR Pulse Width (low)	1000*	—	—	ns	VDD = 5.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
32	TDRT	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	Tioz	I/O Hi-impedance from MCLR Low	100*	300*	1000*	ns	

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 20-7: WDT TIMER TIME-OUT PERIOD vs. $V_{DD}^{(1)}$

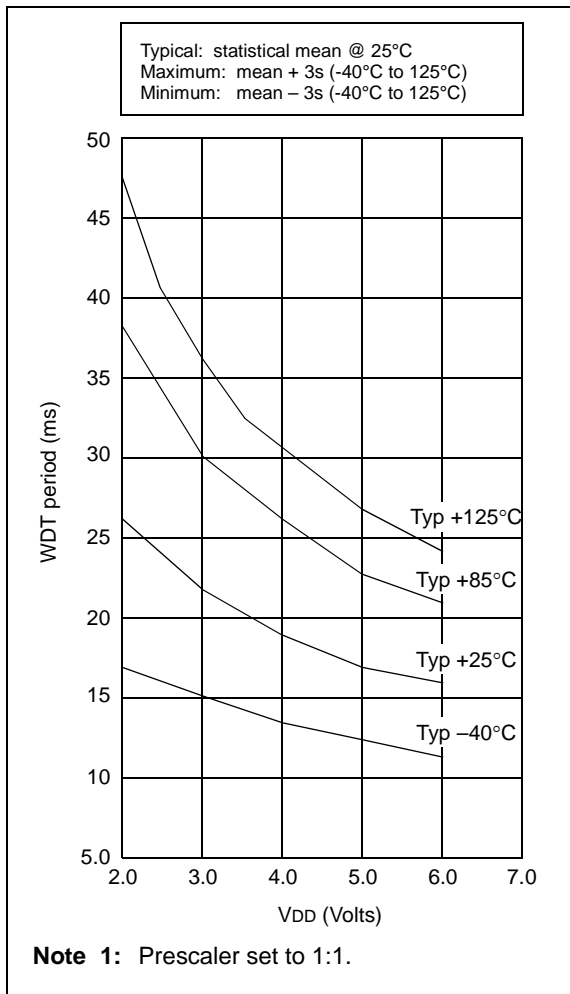


FIGURE 20-8: I_{OH} vs. V_{OH} , $V_{DD} = 5\text{ V}$

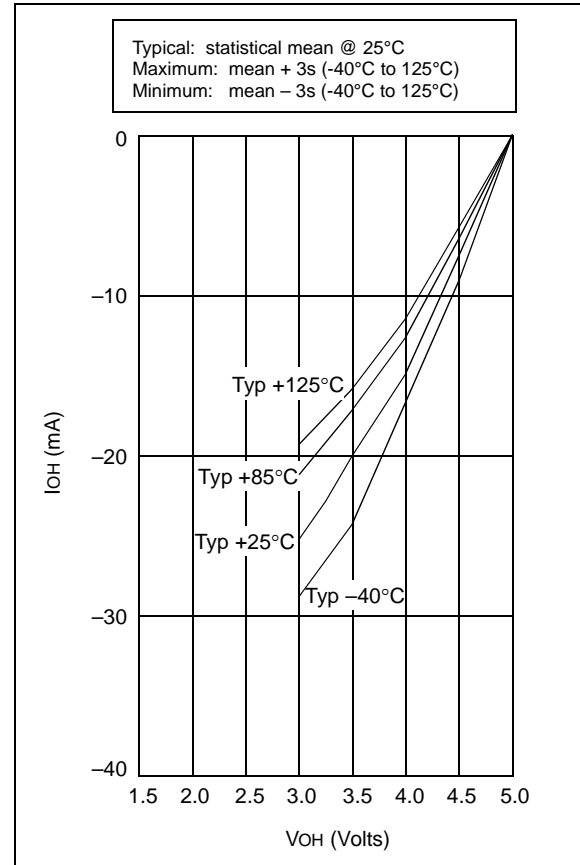


TABLE 20-1: INPUT CAPACITANCE

Pin	Typical Capacitance (pF)	
	18L PDIP	18L SOIC
RA port	5.0	4.3
RB port	5.0	4.3
\overline{MCLR}	17.0	17.0
OSC1	4.0	3.5
OSC2/CLKOUT	4.3	3.5
T0CKI	3.2	2.8

All capacitance values are typical at 25°C. A part-to-part variation of $\pm 25\%$ (three standard deviations) should be taken into account.

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	-	XX	X	/XX	XXX
Device		Frequency Range/OSC Type	Temperature Range	Package	Pattern
Device		PIC16C54 PIC16C54A PIC16CR54A PIC16C54C PIC16CR54C PIC16C55 PIC16C55A PIC16C56 PIC16C56A PIC16CR56A PIC16C57 PIC16C57C PIC16CR57C PIC16C58B PIC16CR58B	PIC16C54T ⁽²⁾ PIC16C54AT ⁽²⁾ PIC16CR54AT ⁽²⁾ PIC16C54CT ⁽²⁾ PIC16CR54CT ⁽²⁾ PIC16C55T ⁽²⁾ PIC16C55AT ⁽²⁾ PIC16C56T ⁽²⁾ PIC16C56AT ⁽²⁾ PIC16CR56AT ⁽²⁾ PIC16C57T ⁽²⁾ PIC16C57CT ⁽²⁾ PIC16CR57CT ⁽²⁾ PIC16C58BT ⁽²⁾ PIC16CR58BT ⁽²⁾		
Frequency Range/ Oscillator Type		RC Resistor Capacitor LP Low Power Crystal XT Standard Crystal/Resonator HS High Speed Crystal 02 200 KHz (LP) or 2 MHz (XT and RC) 04 200 KHz (LP) or 4 MHz (XT and RC) 10 10 MHz (HS only) 20 20 MHz (HS only) 40 40 MHz (HS only) b ⁽⁴⁾ No oscillator type for JW packages ⁽³⁾			
		*RC/LP/XT/HS are for 16C54/55/56/57 devices only -02 is available for 16LV54A only -04/10/20 options are available for all other devices -40 is available for 16C54C/55A/56A/57C/58B devices only			
Temperature Range		b ⁽⁴⁾ = 0°C to +70°C I = -40°C to +85°C E = -40°C to +125°C			
Package		S = Die in Waffle Pack JW = 28-pin 600 mil/18-pin 300 mil windowed CER-DIP ⁽³⁾ P = 28-pin 600 mil/18-pin 300 mil PDIP SO = 300 mil SOIC SS = 209 mil SSOP SP = 28-pin 300 mil Skinny PDIP			
		*See Section 21 for additional package information.			
Pattern		QTP, SQTP, ROM code (factory specified) or Special Requirements. Blank for OTP and Windowed devices.			

Examples:

- PIC16C55A - 04/P 301 = Commercial Temp., PDIP package, 4 MHz, standard VDD limits, QTP pattern #301
- PIC16LC54C - 04I/SO Industrial Temp., SOIC package, 200 kHz, extended VDD limits
- PIC16C57 - RC/SP = RC Oscillator, commercial temp, skinny PDIP package, 4 MHz, standard VDD limits
- PIC16C58BT -40/SS 123 = commercial temp, SSOP package in tape and reel, 4 MHz, extended VDD limits, ROM pattern #123

- Note**
- 1: C = normal voltage range
LC = extended
 - 2: T = in tape and reel - SOIC and SSOP packages only
 - 3: JW Devices are UV erasable and can be programmed to any device configuration. JW Devices meet the electrical requirements of each oscillator type, including LC devices.
 - 4: b = Blank

Sales and Support

Data Sheets

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

1. Your local Microchip sales office
2. The Microchip Worldwide Site (www.microchip.com)

